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Boron nanostructures obtained via ultrasonic irradiation for high performance chemiresistive methane sensors

A chemiresistive device based on boron nanostructure to detect methane gas in the concentration range of 50 ppm - 105 ppm. Boron nanostructures can be obtained via ultrasonication irradiation of micron boron particles. When used as a sensing film in a chemiresistive device, this nanomaterial shows excellent sensitivity towards methane gas. This communication discusses the sonication assisted fabrication of boron nanostructures and subsequent development of a chemiresistive methane gas sensor. The sensitivity, hysteresis, selectivity, and sensing mechanism of the device is also discussed.

As featured in:
Boron nanostructures obtained via ultrasonic irradiation for high performance chemiresistive methane sensors†

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We report on a chemiresistive gas sensor using boron nanostructures as the sensing layer, to detect methane gas down to 50 ppm. The sensor showed an excellent response of 43.5–153.1% for a methane concentration of 50 ppm to 105 ppm, with linear behaviour and good response and recovery time. The stability, repeatability, reproducibility, and shelf life of the sensor are promising for next generation methane gas detection.

Methane is a flammable, colourless, and odourless greenhouse gas which is also the major constituent of natural gas. The detection of methane gas at lower concentration is very important as it can cause a fatal explosion if its concentration reaches 4.9% (49 000 ppm).\(^1\) Apart from this, it has been identified as an excellent biomarker for identifying constipation related diseases.\(^2\) Mostly, detection of a low concentration of methane is possible only by spectroscopy techniques (like mass spectroscopy, radiation spectroscopy etc.); however the high cost and erroneous result when detecting molecules with an identical mass number to atomic number ratio (\(M/Z\)) compelled researchers to look for alternative techniques like electrochemical, chemiresistive diode laser, IR-absorption, optical fiber, fiber-grating, and cataluminescence based methane sensors.\(^3–8\) Among them, chemiresistive sensors have several advantages over others including easy fabrication, integration with the current CMOS technology, and cost effectiveness. Most of the chemiresistive methane sensing devices employ metal oxides and their derivatives as the sensing element. Unfortunately, sensor devices based on these materials usually operate at high temperature which incurs extra cost during fabrication (since the device needs to be integrated with a micro heater), as well as during operation (due to extra power consumed by the micro heater). Recently, layered materials, in particular graphene, boron nitride (BN), transition metal dichalcogenides (TMDs) like WS\(_2\) and MoS\(_2\), and MXenes like transition metal carbides, nitrides, or carbonitrides have emerged as alternatives to these conventional materials.\(^9–15\) Apart from these compounds, nanostructures of many elements have also been investigated for various electronic applications. For instance, sheets of phosphorene which is the most stable allotrope of phosphorous (i.e. black phosphorous) have shown excellent NO\(_2\) gas sensing properties with a limit of detection as low as 20 ppb at room temperature.\(^16\) This has triggered interest in nanostructures of other elements like boron, arsenic etc.\(^17,18\) In particular, recent theoretical reports on prediction of the gas sensing capabilities of borophene are really a great motivation to investigate boron nanostructures for this particular application. Valadbeigi et al. have shown via DFT studies that borophene could possess good selectivity towards carbon monoxide (CO), oxygen (O\(_2\)), and nitrogen monoxide (NO),\(^19\) while Kootenaei et al. demonstrated its sensitivity towards formaldehyde (HCHO) vapors.\(^20\) Rostami et al. found that the surface of borophene is better for NH\(_3\) adsorption at room temperature,\(^21\) while Omidvar has predicted its sensitivity and selectivity towards hydrogen cyanide (HCN).\(^22\) Shukla et al. used a combination of \textit{ab initio} DFT and a nonequilibrium Green’s function (NEGF) based method to predict the gas sensing behaviour of monolayer borophene for analytes like CO, NO, CO\(_2\), NO\(_2\), and NH\(_3\) and demonstrated promising results in terms of adsorption energy, except for CO\(_2\).\(^23\)

It should be noted that borophene is a two-dimensional allotrope of boron which possesses extraordinary electrical, mechanical and electronic properties due its highly anisotropic structure.\(^24,25\) Ultrathin borophene sheets have been realized on noble metal substrates (Ag and Au) by thermal deposition from an ultrapure boron source by electron-beam evaporation.\(^26–29\) However, it can’t be realized \textit{via} liquid exfoliation techniques since a bulk layered counterpart is absent for this synthetic material.\(^30\) Recently, a well-established sonication assisted liquid exfoliation technique was used to fabricate few layered boron sheets using DMF and IPA as the solvent.\(^30\) This stable

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nanomaterial has shown superior performance to the bulk boron when utilized as the supercapacitor electrode material.

In this work we have obtained boron nanostructures by a bath sonication assisted liquid exfoliation method using IPA as the solvent from its bulk counterpart which is a non-layered material in nature. The nanomaterial was characterized with different microscopy techniques, (including field emission scanning electron microscopy (FESEM), transmission electron microscopy (TEM), and atomic force microscopy (AFM)) and spectroscopy techniques (Raman spectroscopy, X-ray photoelectron spectroscopy (XPS), and ultra-violet-visible spectroscopy (UV-Vis)). Subsequently, boron nanostructures have been utilized as the sensing element to detect methane gas down to 50 ppm.

The FESEM image of the bulk boron micron powder (which was used for exfoliation) is shown in Fig. 1(a). After sonication (of this bulk powder without any further processing) for 32 hours in a bath sonicator (250 watt @ 22 °C), and subsequent centrifugation (at 2000 rpm for 30 minutes), a brown suspension from the top (one-third) was collected which is shown in Fig. 1(b). The figure clearly reveals the flat sheet kind of structure; however more morphological data were needed to confirm the 2D-nature. Therefore, the nanostructure of boron was further studied with TEM. The low magnification TEM image, as shown in Fig. 1(c), indicates the true two-dimensional nature of the liquid exfoliated material with lateral dimension in the range of hundreds of nanometres with some of them being ultrathin in nature (as shown in the inset of Fig. 1(c)). TEM was further exploited in studying the crystallinity of the as-obtained boron nanostructures.

The continuous lattice fringe (as shown in Fig. 1(d)) clearly indicates the high crystallinity of the nanostructures, which is further confirmed by the SAED pattern in reciprocal space as shown in Fig. 1(e). A zoomed version of this HRTEM image gives us a lattice spacing of 0.504 nm which corresponds to the (104) plane of β-rhombohedral boron as also reported in the literature recently.  

The AFM results indicate that most of the sheets are 4–10 nm thick with their lateral dimension in the range of a few hundred nanometres to a few microns (thickness vs. lateral dimension plot of a nanostructure is shown in Fig. 1(f)) which is well suited for device fabrication. Seeing the irregular shapes and concave edges of boron nanostructures, we performed Raman measurements of a sample which was scanned by AFM to avoid any confusion with solvent marks. The corresponding Raman data (Fig. S4(b)†) of the sample whose AFM image is shown in Fig. S4(a)† clearly indicate that the nanostructures are truly elemental boron. After morphological confirmation of exfoliation, it was necessary to ascertain the extent of exfoliation. Fig. 2(a) shows the comparison of the X-ray diffraction patterns of bulk boron and exfoliated nanostructures. It is clearly seen that the XRD peaks in the exfoliated boron have shifted to lower two-theta values due to nanostructuring (2θ for bulk boron = 56.28°; 2θ value for the exfoliated boron nanostructure = 56.17°, with change in Δ2θ = 0.11° for (107)). However, the crystallinity of the boron nanostructure is maintained which corroborates the TEM results.

We couldn’t observe any sharp absorption peak in its UV/Vis absorption spectra (as shown in Fig. 2(b)); however, Raman spectroscopy has shown a few notable differences. A comparison of the Raman spectra of bulk boron and boron nanostructures is shown in Fig. 2(c). It is evident that a few suppressed peaks (like those at 531.32 cm−1) have evolved due to new lattice vibrations in boron nanostructures upon exfoliation. Apart from this, the ratio of X and Y peaks (X & Y peaks in boron nanostructures and corresponding peaks in bulk boron are denoted by X’ and Y’) of A1g + E1g Raman active modes and their ratio seem to be very crucial in explaining the extent of exfoliation. For instance, in this case, the intensity ratio of peaks X and Y (Iₓ/Iᵧ) in nanostructured boron is found to be greater than one (Iₓ/Iᵧ > 1) while the ratio of the same peak in bulk boron is less than one (Iₓ/Iᵧ < 1). This may be due to the difference in inter-icosahedral vibration levels in bulk and nanostructured boron. Also, the peak positions of the two peaks are found to be shifted after nanostructuring. A red shift of 1.91 cm−1 is observed in the X peak, while the Y peak shifts significantly (5.94 cm−1) in nanostructured boron compared to its bulk counterpart. However, more systematic studies on the Raman spectrum of boron are needed in the future.

The purity of the element was confirmed through high-angle annular dark-field imaging (HAADF)-scanning transmission electron microscope (STEM) elemental mapping as shown in
Fig. 3. It is clearly evident that abundant oxygen is present in the sample along with the elemental boron. However, the sample hasn’t been oxidised as observed by XRD and spectroscopic characterization. These oxygen molecules may play a crucial role in gas sensing similar to other good gas sensing materials like metal oxides, TMDs, carbon derivatives etc.

The exfoliated boron nanostructures remained well dispersed even after 3 months. No deviation in XRD data of the exfoliated boron nanomaterial after such a long time (as shown in Fig. S9 (ESI†)) clearly indicates that it is stable in ambient atmosphere which further suggests that it is a good choice for receptor materials in chemical sensors.

The exfoliated boron nanostructures were further dropcast on a Ti/Pt (10 nm/90 nm) interdigitated electrode (IDE) of 5 μm gap and calcined at 100 °C for half-an-hour to obtain a two-terminal chemiresistive gas sensing device (more details in ESI Note S1 and optical micrographs in S6, ESI†).

The device was exposed to several oxidising and reducing gases in a custom-built gas sensing set-up (Fig. S1, ESI†), out of which it was found to be selectively responding to CH4 (Fig. S5, ESI†). The dynamic response (%) of the device was obtained by subjecting the device to variable methane concentrations from 105 ppm to 50 ppm and again back to 105 ppm which is shown in Fig. 4(a). It should be noted here that the response (R%) percentage of the device was calculated as

$$R\% = \frac{I_g - I_a}{I_a} \times 100$$ (1)

The first cycle of the device response was fitted to a linear equation (as shown in Fig. 4(b)) and it showed a coefficient of correlation greater than 0.9 (~0.94). The sensitivity (S) of the device is calculated as

$$S(\%) = \frac{I_g - I_a}{I_a} \times 100$$ (2)

We observe a sensitivity of 2.14% ppm$^{-1}$ for the device in the methane concentration range of 50–105 ppm. Another important factor which limits sensor performance is the hysteresis associated with it. Hysteresis depth ($H_{\text{max}}$) associated with the device can be calculated as

$$H_{\text{max}}(\%) = \frac{\Delta R}{Y} \times 100$$ (3)
where $\Delta R$ is the maximum difference between responses in the hysteresis cycle measurement at the same concentration and $Y$ is the overall maximum response in this particular cycle. The hysteresis depth in the device was found to be $\sim 11.28\%$ as calculated from Fig. 4(c).

Furthermore, it was necessary to ascertain the repeatability of the device. Fig. 4(d) shows the gas sensor response for five consecutive methane exposures (of 80 ppm). The device retained a similar rise and fall times for all five cycles in the repeatability test. The sensor was found to be quick enough to respond and recover. The response time and recovery time for 80 ppm methane gas were measured and they were found to be 41.8 seconds and 39.6 seconds, respectively, as shown in Fig. 4(e).

Methane is a non-polar symmetric molecule where a high enthalpy carbon–hydrogen bond gives it more stability in the gaseous phase which makes its dissociation and subsequently its detection tough.

To understand the gas sensing behaviour, it was necessary to understand the chemical and textural properties at the surface of the exfoliated boron nanostructure and its bulk counterpart, which could be done by XPS analysis and nitrogen adsorption—

Fig. 4 (a) Dynamic response of the device to methane gas when it is subjected to 105 ppm to 50 ppm and again 50 ppm to 105 ppm, (b) linearity of the device for one cycle of response (105 ppm to 50 ppm), (c) hysteresis of the device, (d) repeatability of the device when subjected to 80 ppm of methane gas for five consecutive cycles and (e) response and recovery time for 80 ppm of methane gas.
desorption analysis, respectively. The surface states of the exfoliated and bulk boron don’t vary chemically as interpreted from the XPS (XPS survey data are shown in Fig. S10†) signature in B 1s and O 1s spectra as shown in Fig. 5(a–d). The O 1s spectra in both the samples showed a large quantity of surface adsorbed oxygen species. The electron paramagnetic resonance (EPR) measurements in the literature\textsuperscript{33} showed that these surface adsorbed oxygen species easily obtain electrons from the surface of the nanomaterial as follows:

\[ \text{O}_2(\text{gas}) \rightarrow \text{O}_2(\text{ads}) \quad (4) \]

\[ \text{O}_2(\text{ads}) + e^- \rightarrow \text{O}_2(\text{ads})^- \quad (5) \]

When the sensing device is exposed to methane gas, it reacts with the adsorbed oxygen ion species on the boron nanostructures as follows:

\[ \text{CH}_4 + 2\text{O}_2(\text{ads})^- \rightarrow 2\text{H}_2\text{O} + \text{CO}_2 + 2e^- \quad (6) \]

The electrons released in this interaction further increase the conductivity of the boron nanostructures where electrons are the major current carrier. This ionosorption model is widely followed by the sensor community and is highly dependent on the density of oxygen species on the surface which in turn demands high specific area of the nanostructures used as the receptor film.\textsuperscript{34} According to the adsorption–desorption isotherms (Fig. 5(e and f)), the BET surface area of the exfoliated boron sample was determined to be 15.69 m\(^2\) g\(^{-1}\) which is almost 1.74 times that of the bulk boron sample (with BET surface area = 9.04 m\(^2\) g\(^{-1}\)).

The ultrathin nature of the nanostructures ensures the high surface-to-volume ratio which ultimately results in good response. We compared the boron nanostructure based device with other high performance chemiresistive methane sensors as shown in Fig. 6 (with further details in Tables S1 and S2, ESI†) and found that this device is highly competitive, with better or comparable performance with existing technology in terms of experimental limits of detection, response and recovery time, sensitivity, and operating temperature.\textsuperscript{35–46}

Conclusions

We synthesized boron nanostructures via ultrasonic irradiation in a low boiling point solvent medium. A chemiresistive device fabricated with this nanomaterial as the sensing film showed promising methane sensing. In particular, excellent linear response (43.5–153.1\%) for a large range of methane concentrations (50 ppm to 105 ppm), repeatability, and good response and recovery time make this device attractive for the said application. The room temperature operation of the device makes it less power hungry. However, the high hysteresis depth and cross sensitivity associated with the device remain a challenge for the research community and should be addressed for the development of next generation methane sensors.

Conflicts of interest

There are no conflicts to declare.

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